TOSHIBA Transistor Silicon PNP Epitaxial Type

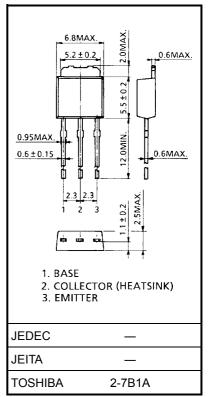
# 2SA1802

## Strobe Flash Applications Medium Power Amplifier Applications

- Excellent hFE linearity
  : hFE (1) = 200 to 600 (VCE = -2 V, IC = -0.5 A)
  : hFE (2) = 140 (min), 200 (typ.) (VCE = -2 V, IC = -3 A)
- Low collector saturation voltage
   VCE (sat) = -0.5 V (max) (IC = -3 A, IB = -60 mA)
   Complementary accurate accurate
- Complementary to 2SC4681

### Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	-30	V	
Collector-emitter voltage		V <sub>CES</sub>	-30	V	
		V <sub>CEO</sub>	-10		
Emitter-base voltage		V <sub>EBO</sub>	-6	V	
Collector current	DC	Ι <sub>C</sub>	-3	А	
	Pulsed (Note 1)	I <sub>CP</sub>	-6		
Base current		Ι <sub>Β</sub>	-0.5	А	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	FC	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Weight: 0.36 g (typ.)

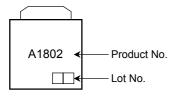
Note 1: Pulse test: Pulse width = 10 ms (max), duty cycle = 30% (max)

Unit: mm

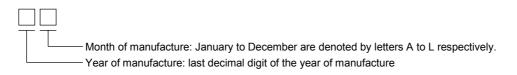
## **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -20 V, I_E = 0$	_	-	-100	nA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -6 V, I_C = 0$	_	_	-100	nA
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0	-10	-	_	V
DC current gain	h <sub>FE (1)</sub>	$V_{CE} = -2 V, I_C = -0.5 A$	200	_	600	
	h <sub>FE (2)</sub>	$V_{CE} = -2 V, I_C = -3 A$	140	200	_	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = -3 A, I <sub>B</sub> = -60 mA	_	-0.25	-0.50	V
Base-emitter voltage	V <sub>BE</sub>	$V_{CE} = -2 V, I_C = -3 A$	_	-0.86	-1.2	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -2 V, I_C = -0.5 A$	_	180	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = -10 V, I <sub>E</sub> = 0, f = 1 MHz	_	50	_	pF

### Marking



## Explanation of Lot No.



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